Features

- KPCS Band CDMA and GPS Operation
- Low Current Consumption
- Excellent Noise and IP3 Performance
- Adjustable Third Order Intercept on LNA Stage
- Flexible IF Frequency Range from 80 MHz to 230 MHz
- Excellent Cross Modulation Performance

Applications

- Quad-mode/Dual-band CDMA IS-95/98 Based Mobile Phones with GPS Support
- Other Familiar Applications

Benefits

- High Linearity Eliminates Potential Call Drop Issues Associated with Gain Switching
- Most Compact Integrated Receiver for K-PCS and A-GPS Applications
- IM98 IMD Requirements Met with two Gain States Simplifying Calibration Procedure
- Best in Class A-GPS CascadeGgain for Maximum Take-over
- TX LO Buffer Included
- Few External Components
- Fully ESD Protected

Electrostatic sensitive device.

Observe precautions for handling.



Description

The T0352 is a CDMA front-end receiver RFIC designed for dual-band, dual-mode operation. The device supports Korean PCS (K-PCS) CDMA and A-GPS operation. The IF range is from 80 MHz to 230 MHz with external tuning. The K-PCS low noise amplifier has an adjustable third order intercept (IP3) to minimize inter-modulation and cross-modulation effects. The mixers are designed for differential IF outputs (single-ended or differential IF outputs for GPS modes), and they feature excellent linearity and low noise figure.

The T0352 device is available in a 4 mm \times 4 mm MLF package with 24 pins. This front-end receiver is capable of meeting all electrical requirements in accordance with the TIA/EIA 98-C Wireless Communication standard.



2.8 V Dual-band/ Dual-mode RF Receiver for K-PCS/GPS

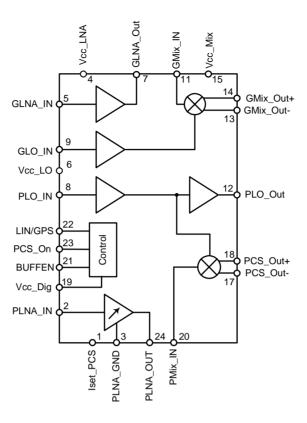
T0352

Preliminary (Summary)



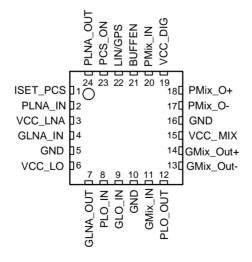


Figure 1. Block Diagram



Pin Configuration

Figure 2. Pinning HP-VFQFP-N24



Pin Description

Pin	Symbol	Function
1	Iset_PCS	Bias resistor for K-PCS LNA. For typical bias use a 560 Ω resistor to ground which set the bias current for HGHL mode.
2	PLNA_IN	PCS LNA input. Requires a DC blocking capacitor and an L-C (shunt C/series L) matching network for optimum gain, intercept and noise performance.
3	Vcc_LNA	Power supply pin for K-PCS LNA. Bypass with a capacitor as close to the pin as possible.
4	GLNA_IN	GPS LNA input. Requires LC match, see Pin 2.
5	GLNA_GND	GPS LNA emitter-ground. The LNA emitter ground should be grounded immediately to the ground plane to reduce stray inductance and capacitance that may affect performance.
6	Vcc_LO	Supply voltage for LO buffer.
7	GLNA_OUT	GPS LNA output.
8	PLO_IN	K-PCS LO input.
9	GLO_IN	GPS LO input.
10	GND	Device ground.
11	GMix_IN	GPS mixer input.
12	PLO_OUT	K-PCS LO buffer output. Internally matched to 100 Ω . Does not require a blocking capacitor.
13	GMix_OUT-	Negative GPS IF output.
14	GMix_OUT+	Positive GPS IF output.
15	Vcc_Mix	Supply voltage for all mixers.
16	GND	Device ground.
17	PMix_OUT-	Negative CDMA IF output.
18	PMix_OUT+	Positive CDMA IF output.
19	Vcc_DIG	Supply voltage for logic control circuits.
20	PMix_IN	K-PCS Mixer RF input.
21	BUFFEN	LO output buffer enable. Set BUFFEN pin HIGH to power up the PCS LO buffer output.
22	LIN/GPS	-
23	PCS_ON	Logic input for activating PCS LNA; Logic high selects PCS. Logic low means inactive.
24	PLNA_OUT	PCS LNA output. Requires a pull-up inductor to Vcc and a series blocking capacitor, which can be used as the output matching network.
_	Paddle	Device ground and heat sink, requires good thermal path; RF reference plane.
_	Paddle	Device ground and heat sink, requires good thermal path; RF reference plane.





Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Supply voltages, no RF applied	V _{CC}	-0.5 to +4.0	V
Logic control voltages	V _{CTRL}	-0.5 to + V _{CC} +0.5	V
Supply current	I _{cc}	50.0	mA
RF and LO input signals	P _{LO;} G _{LO;} PLNA_IN; GLNA_IN;	5.0	dBm
I _{SET_PCS} ; I _{SET_CELL}	LNA IP3 Adjustment	1	mA
Operating case temperature	T _C	-40 to +100	°C
Storage temperature	T _{STG}	-55 to +150	°C

Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	R _{thJA}	TBD	K/W

DC Supply Characteristics

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions (no RF applied): $V_{CC} = +2.75 \text{ V}$, $T_{amb} = 25^{\circ}\text{C}$.

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Тур.	Max.	Unit	Type*
	All Modes				•			'	'
	Supply voltage		3, 15, 19	V _{CC}	2.7	2.8	3.3	V	
	Control voltage high		23, 21, 22	V _{CTRL}	1.7			V	
	Control voltage low		21, 22, 23	V _{CTRL}			0.5	V	
	LO Rx buffer supply current		15	I _{CC_MIX}		7.0		mA	
	LO Tx buffer current	BUFFEN = High	15	I _{CC_MIX}		6.0		mA	
	Logic-high current		21, 22, 23	I _{CTRL}			100	μA	
	Logic-low current		21, 22, 23	I _{CTRL}	-5.0			μA	
	Power-down supply current	PCS_On, LIN = Low	3, 13, 14, 15, 17, 18, 19, 24	I _{cc}			10	μA	

^{*)} Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

AC Electrical Characteristics

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions: $V_{CC} = +2.75 \text{ V}$, $T_{amb} = 25^{\circ}\text{C}$, all RF inputs and outputs with a return loss of 10 dB minimum.

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Тур.	Max.	Unit	Type*
	General Performance								
	Operating frequency	K-PCS band	2, 20	f _{PCS}	1840	1855	1870	MHz	
	range	A-GPS band	4, 11	f _{GPS}		1575.42		MHz	
	LO frequency range	K-PCS band:	8	f _{LOPCS}	1656		1686	MHz	
		IF = 183.6 MHz	8	f _{LOPCS}	2023		2053	MHz	
		GPS band:	9	f _{LOGPS}		1391.82		MHz	
		IF = 183.6 MHz	9	f _{LOGPS}		1759.02		MHz	
	IF frequency range	K-PCS and GPS Band	13, 14, 17, 18	f _{IF}	80	85	230	MHz	
	LO input power level	K-PCS and GPS Band	8, 9	P_{LO}	-10	-5	0	dBm	
	LO Tx buffer output power level	K-PCS band; not matched at dedicated frequency	12	P _{LOOUT}	-8	-3		dBm	

^{*)} Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Cascade RF Electrical Characteristics (K-PCS Band)

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions: $V_{CC} = +2.75 \text{ V}$, $T_{amb} = 25^{\circ}\text{C}$, RF = 1960 MHz; LO = 2045 MHz; IF = 85 MHz; LO input = -5.0 dBm; RF input = -30 dBm (high gain mode)

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Тур.	Max.	Unit	Type*	
	Combined LNA and	d Mixer Performance (CD	MA Modul	ation)	"					
	High-gain High-line	High-gain High-linearity Mode (HGHL)								
	Gain			G		26		dB		
	Noise figure	PCS_On = High;		NF		2.2		dB		
	Input IP3	LIN = High		IIP3		-1.5		dBm		
	Supply current			I _{cc}		30		mA		
	High-gain Low-line	earity Mode (HGLL, Pagin	g Mode)	•	•	•	•	•		
	Gain			G		25.3		dB		
	Noise figure	PCS_On = High;		NF		2.2		dB		
	Input IP3	LIN = Low		IIP3		-5.3		dBm		
	Supply current			I _{cc}		24		mA		

^{*)} Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter





Cascade RF Electrical Characteristics (GPS Band)

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions: $V_{CC} = +2.75 \text{ V}$, $T_{amb} = 25^{\circ}\text{C}$, RF = 1575.42 MHz; LO = 1490.42 MHz; IF = 85 MHz; LO input = -5.0 dBm; RF input = -45 dBm

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Тур.	Max.	Unit	Type*
	Combined LNA and N	Combined LNA and Mixer Performance							
	A-GPS LNA PERFORMANCE								
	Gain			G		37		dB	
	Noise figure	PCS_On = Low;		NF		1.5		dB	
	Input IP3	LIN = High		IIP3		-17.5		dBm	
	Supply current			I _{cc}		21		mA	

^{*)} Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Typical Electrical Characteristics LNA and Mixer Separately (K-PCS Band)

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions: $V_{CC} = +2.75 \text{ V}$, $T_{amb} = 25^{\circ}\text{C}$, RF = 1960 MHz; LO = 2045 MHz; IF = 85 MHz; LO input = -5.0 dBm; RF input = -25 dBm (high gain mode)

No.	Parameters	Test Conditions	Gain (dB)	NF (dB)	IIP3 (dBm)	Type*	
	K-PCS Band, High-gain High-linearity Mode (HGHL); CDMA Modulation						
	K-PCS LNA	PCS_On = High; LIN = High	15.5	1.6	9.0		
	K-PCS mixer		13.5	6.2	11.0		
	K-PCS Band, High-gain Low-linearity Mode (HGLL); CDMA Modulation						
	K-PCS LNA	PCS_On = High; LIN = Low	15	1.6	7.5		
	K-PCS mixer	PCS_OII = HIGH, LIN = LOW	13.3	6.0	7.5		

^{*)} Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Typical Electrical Characteristics LNA and Mixer separately (GPS Band)

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions: V_{CC} = +2.75 V, T_{amb} = 25°C, RF = 1575.42 MHz; LO = 1490.42 MHz; IF = 85 MHz; LO input = -5.0 dBm; RF input = -35 dBm

No.	Parameters	Test Conditions	Gain (dB)	NF (dB)	IIP3 (dBm)	Type*
	A-GPS Mode					
	GPS LNA	DCS On - High: LIN - Low	19.5	1.5	-2.8	
	GPS Mixer	PCS_On = High; LIN = Low	17.5	5.9	-3.0	

^{*)} Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Ordering Information

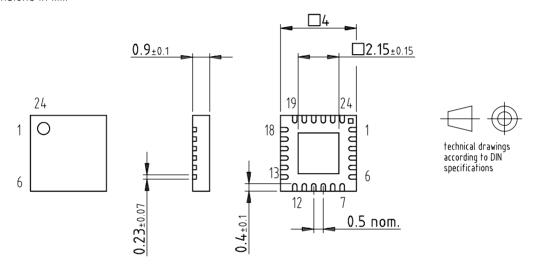
Extended Type Number	Package	Remarks
T0352	HP-VFQFP-N24	4 mm × 4 mm

Package Information

Package: HP-VFQFP-N24

(acc. JEDEC OUTLINE No. MO-220)

Dimensions in mm



Drawing-No.: 6.543-5086.01-4

Issue: 1; 26.02.02

Note: 1. GND solder mask opening is not centered on the package.





Atmel Headquarters

Corporate Headquarters 2325 Orchard Parkway San Jose, CA 95131 TEL 1(408) 441-0311 FAX 1(408) 487-2600

Europe

Atmel Sarl Route des Arsenaux 41 Case Postale 80 CH-1705 Fribourg Switzerland TEL (41) 26-426-5555 FAX (41) 26-426-5500

Asia

Room 1219 Chinachem Golden Plaza 77 Mody Road Tsimhatsui East Kowloon Hong Kong TEL (852) 2721-9778 FAX (852) 2722-1369

Japan

9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033 Japan TEL (81) 3-3523-3551 FAX (81) 3-3523-7581

Atmel Operations

Memory

2325 Orchard Parkway San Jose, CA 95131 TEL 1(408) 441-0311 FAX 1(408) 436-4314

Microcontrollers

2325 Orchard Parkway San Jose, CA 95131 TEL 1(408) 441-0311 FAX 1(408) 436-4314

La Chantrerie BP 70602 44306 Nantes Cedex 3, France TEL (33) 2-40-18-18-18 FAX (33) 2-40-18-19-60

ASIC/ASSP/Smart Cards

Zone Industrielle 13106 Rousset Cedex, France TEL (33) 4-42-53-60-00 FAX (33) 4-42-53-60-01

1150 East Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 TEL 1(719) 576-3300 FAX 1(719) 540-1759

Scottish Enterprise Technology Park Maxwell Building East Kilbride G75 0QR, Scotland TEL (44) 1355-803-000 FAX (44) 1355-242-743

RF/Automotive

Theresienstrasse 2 Postfach 3535 74025 Heilbronn, Germany TEL (49) 71-31-67-0 FAX (49) 71-31-67-2340

1150 East Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 TEL 1(719) 576-3300 FAX 1(719) 540-1759

Biometrics/Imaging/Hi-Rel MPU/ High Speed Converters/RF Datacom

Avenue de Rochepleine BP 123 38521 Saint-Egreve Cedex, France TEL (33) 4-76-58-30-00 FAX (33) 4-76-58-34-80

e-mail literature@atmel.com

Web Site http://www.atmel.com

© Atmel Corporation 2002.

Atmel Corporation makes no warranty for the use of its products, other than those expressly contained in the Company's standard warranty which is detailed in Atmel's Terms and Conditions located on the Company's web site. The Company assumes no responsibility for any errors which may appear in this document, reserves the right to change devices or specifications detailed herein at any time without notice, and does not make any commitment to update the information contained herein. No licenses to patents or other intellectual property of Atmel are granted by the Company in connection with the sale of Atmel products, expressly or by implication. Atmel's products are not authorized for use as critical components in life support devices or systems.

Atmel® is the registered trademark of Atmel.

Other terms and product names may be the trademarks of others.

